



30V P-Channel Enhancement Mode MOSFET

Voltage

-30 V

Current

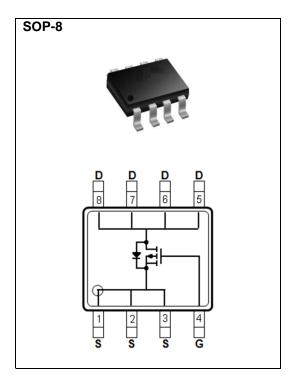
-15A

Features

- R_{DS(ON)}, V_{GS}@-10V, I_D@-15A<4.5mΩ
- R_{DS(ON)}, V_{GS}@-4.5V, I_D@-10A<7mΩ
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std.. (Halogen Free)

Mechanical Data

- Case: SOP-8 package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0029 ounces, 0.083 grams



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS | |
|--|----------------------|---------------------|-------------|-------|--|
| Drain-Source Voltage | | V _{DS} | -30 | V | |
| Gate-Source Voltage | | V_{GS} | <u>+</u> 20 | V | |
| Continuous Drain Current | T _A =25°C | l _D | -15 | | |
| | T _A =70°C | | -12 | Α | |
| Pulsed Drain Current (Note 1) | | I _{DM} | -72 | Α | |
| Power Dissipation | T _A =25°C | P _D | 1.7 | 147 | |
| | T _A =70°C | | 1.1 | W | |
| Operating Junction and Storage Temperature Range | | T_{J} , T_{STG} | -55~150 | °C | |
| Typical Thermal Resistance | | | | | |
| - Junction to Ambient (Note 5) | | $R_{\theta JA}$ | 73.5 | °C/W | |





Electrical Characteristics (T_A=25 °C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS | |
|----------------------------------|---------------------|---|------|-------|--------------|-------|--|
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V,I _D =-250uA | -30 | - | - | V | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}$, $I_{D}=-250uA$ | -1 | -1.6 | -2.5 | | |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =-10V,I _D =-15A | - | 3.9 | 4.5 | mΩ | |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =-4.5V,I _D =-10A | - | 5.7 | 7 | | |
| Zero Gate Voltage Drain Current | I _{DSS} | V_{DS} =-30V, V_{GS} =0V | - | - | -1 | uA | |
| Gate-Source Leakage Current | I _{GSS} | V _{GS} = <u>+</u> 20V,V _{DS} =0V | - | - | <u>+</u> 100 | nA | |
| Dynamic (Note 6) | | | | | | | |
| Total Gate Charge | Q_g | V _{DS} =-15V, I _D =-10A, V _{GS} =-10V ^(Note 2,3) | - | 107 | - | nC | |
| Gate-Source Charge | Q_gs | | - | 18 | - | | |
| Gate-Drain Charge | Q_gd | | - | 18 | - | | |
| Input Capacitance | Ciss | V _{DS} =-25V, V _{GS} =0V, f=1.0MHZ | - | 6067 | - | pF | |
| Output Capacitance | Coss | | - | 709 | - | | |
| Reverse Transfer Capacitance | Crss | | - | 361 | - | | |
| Turn-On Delay Time | td _(on) | \/ 45\/ L 4A | - | 22 | - | ns | |
| Turn-On Rise Time | tr | $\begin{array}{c} V_{DS}\text{=-}15V,I_{D}\text{=-}1A,\\ V_{GS}\text{=-}10V,\ R_{G}\text{=}6\Omega\\ \text{(Note 2,3)} \end{array}$ | - | 48 | - | | |
| Turn-Off Delay Time | td _(off) | | - | 197 | - | | |
| Turn-Off Fall Time | tf | | - | 90 | - | | |
| Drain-Source Diode | | | | | | | |
| Maximum Continuous Drain-Source | | | - | - | -15 | А | |
| Diode Forward Current | I _S | | | | | | |
| Diode Forward Voltage | V_{SD} | I _S =-1A, V _{GS} =0V | - | -0.68 | -1.0 | V | |

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

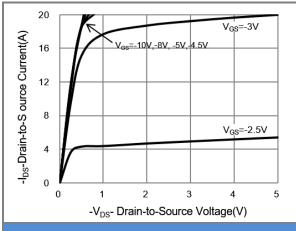


Fig.1 On-Region Characteristics

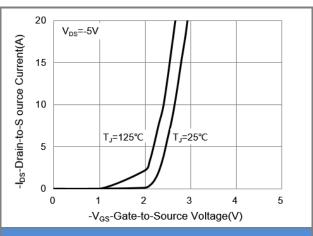


Fig.2 Transfer Characteristics

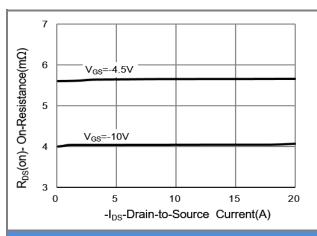


Fig.3 On-Resistance vs. Drain Current

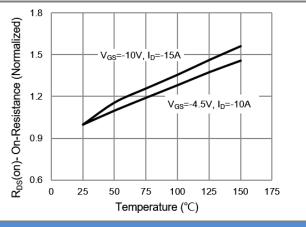


Fig.4 On-Resistance vs. Junction temperature

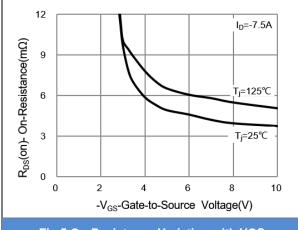


Fig.5 On-Resistance Variation with VGS.

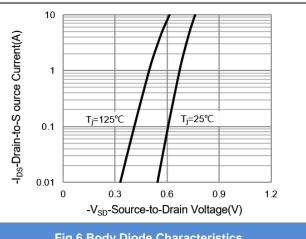


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

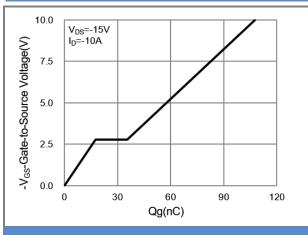


Fig.7 Gate-Charge Characteristics

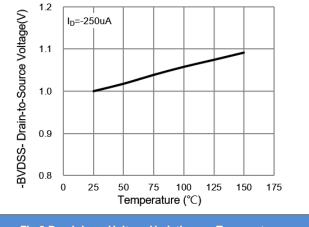


Fig.8 Breakdown Voltage Variation vs. Temperature

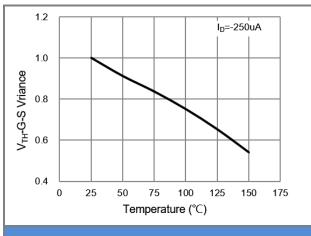


Fig.9 Threshold Voltage Variation with Temperature.

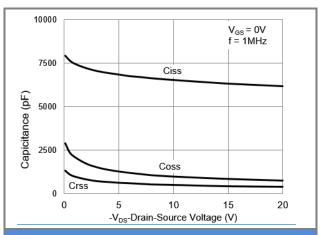


Fig.10 Capacitance vs. Drain-Source Voltage.

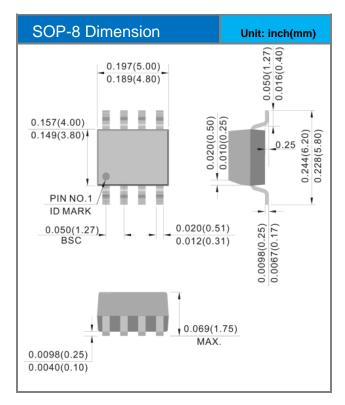


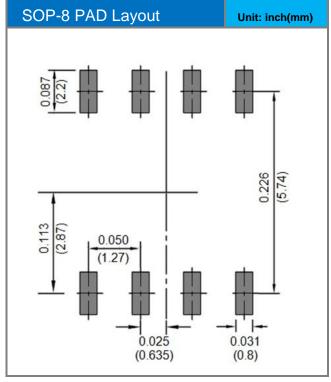


Part No Packing Code Version

| Part No Packing Code | Package Type | Packing Type | Marking | Version |
|----------------------|--------------|---------------------|---------|--------------|
| PJL9417_R2_00001 | SOP-8 | 2.5K pcs / 13" reel | L9417 | Halogen free |

Packaging Information & Mounting Pad Layout









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